

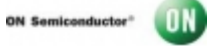


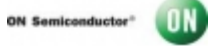




	<p><b>NTP5412NG</b></p>
	<p><b>Hersteller-Teilenummer:</b> NTP5412NG</p>
	<p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p>
	<p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 60A TO-220AB</p>
	<p><b>Datenblätter:</b>  <a href="#">NTP5412NG.pdf</a></p>
	<p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p>
	<p><b>Lagerzustand:</b> New original, 5100 pcs Stock Available.</p>
	<p><b>Liefern von:</b> Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>

### Spezifikationen

Teilenummer	NTP5412NG
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 60A TO-220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5100 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	125W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	60A (Tc)
Rds On (Max) @ Id, Vgs	14 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	85nC @ 0V
Eingabekapazität (Ciss) (Max) @ Vds	3220pF @ 25V
Verpackung	Tube



















































NTP5412NG ist neu im Original, Suche NTP5412NG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTP5412NG AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTP5412NG: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>NTP5404N</b> AMI Semiconductor / ON Semiconductor NTP5404N ON</p>	 <p><b>NTP52N10G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 60A TO220AB</p>	 <p><b>NTP5860NL</b> O NTP5860NL O</p>	 <p><b>NTP5426N</b> AMI Semiconductor / ON Semiconductor NTP5426N ON</p>
 <p><b>NTP5860NG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 220A TO-220-3</p>	 <p><b>NTP5404NRG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 136A TO220AB</p>	 <p><b>NTP5411NG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 80A TO-220AB</p>	 <p><b>NTP5860N</b> VB NTP5860N VB</p>

### heiße Teile

Mehr

 NTP18N06G	 NTP18N06L	 NTP18N06LG	 NTP22N06	 NTP22N06L
 NTP27N06G	 NTP27N06L	 NTP2955G	 NTP30N06L	 NTP30N06LG
 NTP30N20	 NTP30N20G	 NTP35N15	 NTP35N15G	 NTP4302G
 NTP45N06	 NTP45N06G	 NTP45N06L	 NTP45N06LG	 NTP477M04TDR
 NTP52N10	 NTP52N10G	 NTP5404N	 NTP5404NRG	 NTP5411NG
 NTP5426N	 NTP5426NG	 NTP5860N	 NTP5860NG	 NTP5860NL
 NTP5860NLG	 NTP5862NG	 NTP5863N	 NTP5863NG	 NTP5864N
 NTP5864NG	 NTP60N06	 NTP60N06G	 NTP60N06L	 NTP60N06LG
 NTP6410AN	 NTP6410ANG	 NTP6411AN	 NTP6411ANG	 NTP6412AN
 NTP6412ANG	 NTP6413AN	 NTP6413ANG	 NTP6448ANG	 NTP65N02R

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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